Thyristor Semiconductor Device - Page 1 of 1



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### **Inclosure Material:**

Metal

**Overall Length:** 

0.235 inches

# **Terminal Length:**

1.320 inches

# **Overall Diameter:**

0.430 inches

## Mounting Method:

Terminal

### **Features Provided:**

Hermetically sealed case

## Semiconductor Material:

Silicon

# Voltage Rating In Volts Per Characteristic:

100.0 repetitive peak reverse voltage, peak total value, gate terminal open-circuited and 150.0 nonrepetitive peak reverse voltage, peak total value, gate terminal open-circuited

# **Current Rating Per Characteristic:**

8.00 amperes source cutoff current preset and 100.00 amperes forward current, average preset and 2.00 amperes zero-gate-voltage source current horsepower metric

# **Power Rating Per Characteristic:**

5.0 watts small-signal input power, common-collector outside diameter and 0.5 watts small-signal input power, common-collector peak

# Maximum Operating Tempurature Per Measurement Point:

100.0 degrees celsius junction

# **Test Data Document:**

35351-151706 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

# Terminal Type And Quantity:

3 uninsulated wire lead

Shelf Life:

N/a

#### Unit Of Measure:

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#### **Demilitarization:**

No

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